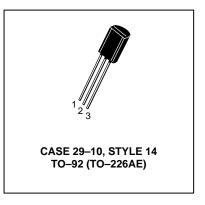


One Watt Amplifier Transistor NPN Silicon

BDC01D

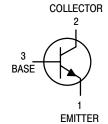
MAXIMUM RATINGS

| Rating | Symbol | BDC01D | Unit |
|---|-----------------------------------|-------------|----------------|
| Collector–Emitter Voltage | V _{CEO} | 100 | Vdc |
| Collector–Base Voltage | V _{CBO} | 100 | Vdc |
| Emitter–Base Voltage | V _{EBO} | 5.0 | Vdc |
| Collector Current — Continuous | I _C | 0.5 | Adc |
| Total Device Dissipation @ T _A = 25°C Derate above 25°C | P _D | 1.0 8.0 | Watts mW/°C |
| Total Device Dissipation @ T _C = 25°C Derate above 25°C | P _D | 2.5 20 | Watts mW/°C |
| Operating and Storage Junction Temperature Range | T _J , T _{stg} | -55 to +150 | °C |



THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|---|-----------------|-----|------|
| Thermal Resistance, Junction to Ambient | $R_{	heta JA}$ | 125 | °C/W |
| Thermal Resistance, Junction to Case | $R_{\theta JC}$ | 50 | °C/W |



ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

| Characteristic | Symb ol | Min | Max | Unit | |
|----------------|------------|-----|-----|------|--|
|----------------|------------|-----|-----|------|--|

OFF CHARACTERISTICS

| Collector–Emitter Voltage (I _C = 10 mA, I _B = 0) | V _{(BR)C} EO | 100 | | Vdc |
|---|--------------------------|-----|-----|------|
| Collector Cutoff Current (V _{CB} = 100 V, I _E = 0) | I _{CBO} | _ | 0.1 | μAdc |
| Emitter Cutoff Current (I _C = 0, V _{EB} = 5.0 V) | I _{EBO} | _ | 100 | nAdc |

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

| Characteristic | Symbol | Min | Max | Unit | |
|---|-----------------|----------|----------|------|--|
| ON CHARACTERISTICS | | | | | |
| DC Current Gain $(I_C = 100 \text{ mA}, V_{CE} = 1.0 \text{ V})$ $(I_C = 500 \text{ mA}, V_{CE} = 2.0 \text{ V})$ | h _{FE} | 40 25 | 400 — | _ | |
| Collector–Emitter Saturation Voltage ⁽¹⁾ (I _C = 1000 mA, I _B = 100 mA) | | _ | 0.7 | Vdc | |
| Collector–Emitter On Voltage ⁽¹⁾ (I _C = 1000 mA, V _{CE} = 1.0 V) | | _ | 1.2 | Vdc | |
| DYNAMIC CHARACTERISTICS | | | | | |
| Current Gain Bandwidth Product (I _C = 200 mA, V _{CE} = 5.0 V, f = 20 MHz) | | 50 | _ | MHz | |
| Output Capacitance $(V_{CB} = 10 \text{ V}, I_E = 0, f = 1.0 \text{ MHz})$ | | _ | 30 | pF | |

^{1.} Pulse Test: Pulse Width \leq 300 μ s; Duty Cycle 2.0%.

BDC01D

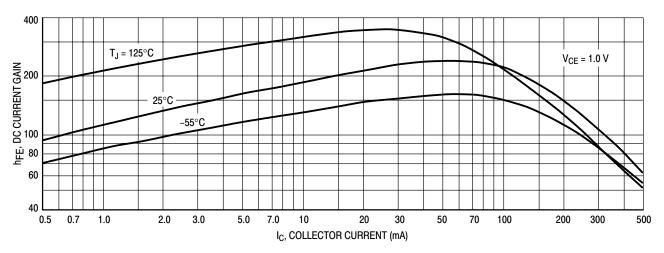


Figure 1. DC Current Gain

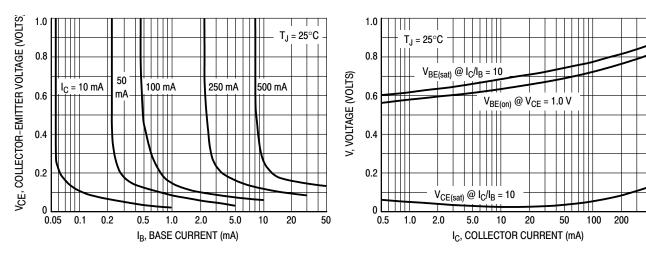


Figure 2. Collector Saturation Region

Figure 3. "On" Voltages

500

BDC01D

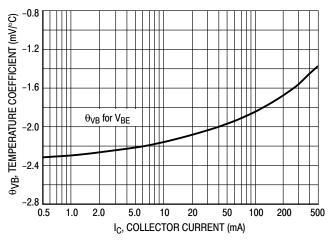


Figure 4. Base–Emitter Temperature Coefficient

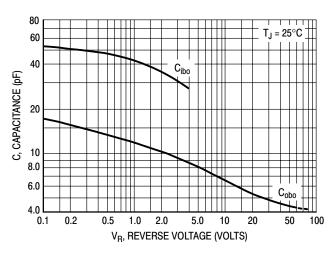


Figure 5. Capacitance

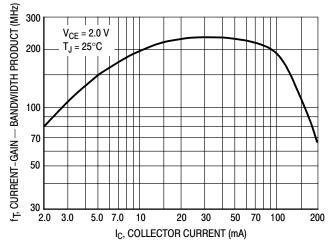


Figure 6. Current-Gain — Bandwidth Product

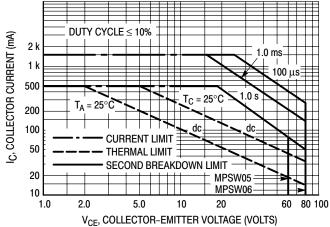
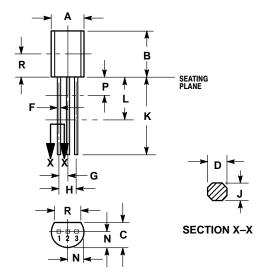


Figure 7. Active Region — Safe Operating Area

BDC01D

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-10 ISSUE AL



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2 CONTROLLING DIMENSION: INCH
- CONTOUR OF PACKAGE BEYOND DIMENSION R
 IS LINCONTROLLED.
- IS UNCONTROLLED.

 4. DIMENSION F APPLIES BETWEEN P AND L
 DIMENSIONS D AND J APPLY BETWEEN LAND K
 MIMIMUM. LEAD DIMENSION IS UNCONTROLLED
 IN P AND BEYOND DIMENSION K MINIMUM.

| | INCHES | | MILLIN | ETERS | |
|-----|--------|-------|--------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 0.175 | 0.205 | 4.44 | 5.21 | |
| В | 0.290 | 0.310 | 7.37 | 7.87 | |
| С | 0.125 | 0.165 | 3.18 | 4.19 | |
| D | 0.018 | 0.021 | 0.457 | 0.533 | |
| F | 0.016 | 0.019 | 0.407 | 0.482 | |
| G | 0.045 | 0.055 | 1.15 | 1.39 | |
| Н | 0.095 | 0.105 | 2.42 | 2.66 | |
| J | 0.018 | 0.024 | 0.46 | 0.61 | |
| K | 0.500 | | 12.70 | | |
| L | 0.250 | | 6.35 | | |
| N | 0.080 | 0.105 | 2.04 | 2.66 | |
| P | | 0.100 | | 2.54 | |
| R | 0.135 | | 3.43 | | |

YLE 14:

1. EMITTER
2. COLLECTOR

B. BASE

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